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REVISION HISTORY

5/2019—Rev. L to Rev. M

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5/2018—Rev. K to Rev. L

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10/2017—Rev. J to Rev. K

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Added Solder Heat Effect Section	12
Added Figure 14; Renumbered Sequentially	12
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2/2013—Rev. I to Rev. J

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6/2006—Rev. F to Rev. G

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2/2006—Rev. E to Rev. F

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3/1997—Revision 0: Initial Version

SPECIFICATIONS

AD1582 SPECIFICATIONS

$T_A = T_{MIN}$ to T_{MAX} , $V_{IN} = 5$ V, unless otherwise noted.

Table 2.

Parameter	AD1582A			AD1582B			Unit
	Min	Typ	Max	Min	Typ	Max	
OUTPUT VOLTAGE (at 25°C) V_O	2.480	2.500	2.520	2.498	2.500	2.502	V
INITIAL ACCURACY ERROR (at 25°C) V_{OERR}	−20		+20	−2		+2	mV
	−0.80		+0.80	−0.08		+0.08	%
V_{OERR} (W-Grade)				−6		+6	mV
				−0.24		+0.24	%
OUTPUT VOLTAGE TEMPERATURE DRIFT			100			50	ppm/°C
TEMPERATURE COEFFICIENT (TCV _O) −40°C < T_A < +125°C		40	100		18	50	ppm/°C
0°C < T_A < 70°C		35			15		ppm/°C
MINIMUM SUPPLY HEADROOM ($V_{IN} - V_{OUT}$)	200			200			mV
LOAD REGULATION							
0 mA < I_{OUT} < 5 mA (−40°C to +85°C)			0.2			0.2	mV/mA
0 mA < I_{OUT} < 5 mA (−40°C to +125°C)			0.4			0.4	mV/mA
−5 mA < I_{OUT} < 0 mA (−40°C to +85°C)			0.25			0.25	mV/mA
−5 mA < I_{OUT} < 0 mA (−40°C to +125°C)			0.45			0.45	mV/mA
−0.1 mA < I_{OUT} < +0.1 mA (−40°C to +85°C)			2.7			2.7	mV/mA
−0.1 mA < I_{OUT} < +0.1 mA (−40°C to +125°C)			3.5			3.5	mV/mA
LINE REGULATION $V_{OUT} + 200$ mV < V_{IN} < 12 V $I_{OUT} = 0$ mA			25			25	μV/V
RIPPLE REJECTION ($\Delta V_{OUT}/\Delta V_{IN}$) $V_{IN} = 5$ V ± 100 mV (f = 120 Hz)	80			80			dB
QUIESCENT CURRENT		70			70		μA
SHORT-CIRCUIT CURRENT TO GROUND		15			15		mA
NOISE VOLTAGE (at 25°C) 0.1 Hz to 10 Hz 10 Hz to 10 kHz		70 50			70 50		μV p-p μV rms
TURN-ON SETTLING TIME TO 0.1% $C_L = 0.2$ μF		100			100		μs
LONG-TERM STABILITY 1000 Hours at 25°C		100			100		ppm/1000 hr
OUTPUT VOLTAGE HYSTERESIS		115			115		ppm
TEMPERATURE RANGE Specified Performance (A, B) Operating Performance (A, B)	−40 −55		+125 +125	−40 −55		+125 +125	°C °C

AD1583 SPECIFICATIONS

$T_A = T_{MIN}$ to T_{MAX} , $V_{IN} = 5$ V, unless otherwise noted.

Table 3.

Parameter	AD1583A			AD1583B			Unit
	Min	Typ	Max	Min	Typ	Max	
OUTPUT VOLTAGE (at 25°C) V_O	2.970	3.000	3.030	2.997	3.000	3.003	V
INITIAL ACCURACY ERROR (at 25°C) V_{OERR}	−30		+30	−3		+3	mV
	−1.0		+1.0	−0.1		+0.1	%
V_{OERR} (W Grade)				−8		+8	mV
				−0.27		+0.27	%
OUTPUT VOLTAGE TEMPERATURE DRIFT			100			50	ppm/°C
TEMPERATURE COEFFICIENT (TCV _O) −40°C < T_A < +125°C		40	100		18	50	ppm/°C
0°C < T_A < 70°C		35			15		ppm/°C
MINIMUM SUPPLY HEADROOM ($V_{IN} - V_{OUT}$)	200			200			mV
LOAD REGULATION							
0 mA < I_{OUT} < 5 mA (−40°C to +85°C)			0.25			0.25	mV/mA
0 mA < I_{OUT} < 5 mA (−40°C to +125°C)			0.45			0.45	mV/mA
−5 mA < I_{OUT} < 0 mA (−40°C to +85°C)			0.40			0.40	mV/mA
−5 mA < I_{OUT} < 0 mA (−40°C to +125°C)			0.6			0.6	mV/mA
−0.1 mA < I_{OUT} < +0.1 mA (−40°C to +85°C)			2.9			2.9	mV/mA
−0.1 mA < I_{OUT} < +0.1 mA (−40°C to +125°C)			3.7			3.7	mV/mA
LINE REGULATION $V_{OUT} + 200$ mV < V_{IN} < 12 V $I_{OUT} = 0$ mA			25			25	μV/V
RIPPLE REJECTION ($\Delta V_{OUT}/\Delta V_{IN}$) $V_{IN} = 5$ V ± 100 mV (f = 120 Hz)	80			80			dB
QUIESCENT CURRENT			70			70	μA
SHORT-CIRCUIT CURRENT TO GROUND			15			15	mA
NOISE VOLTAGE (at 25°C) 0.1 Hz to 10 Hz 10 Hz to 10 kHz		85 60			85 60		μV p-p μV rms
TURN-ON SETTLING TIME TO 0.1% $C_L = 0.2$ μF			120			120	μs
LONG-TERM STABILITY 1000 Hours at 25°C		100			100		ppm/1000 hr
OUTPUT VOLTAGE HYSTERESIS		115			115		ppm
TEMPERATURE RANGE Specified Performance (A, B) Operating Performance (A, B)	−40 −55		+125 +125	−40 −55		+125 +125	°C °C

AD1584 SPECIFICATIONS

$T_A = T_{MIN}$ to T_{MAX} , $V_{IN} = 5$ V, unless otherwise noted.

Table 4.

Parameter	AD1584A			AD1584B			Unit
	Min	Typ	Max	Min	Typ	Max	
OUTPUT VOLTAGE (at 25°C) V_O	4.056	4.096	4.136	4.092	4.096	4.100	V
INITIAL ACCURACY ERROR (at 25°C) V_{OERR}	−40 −0.98		+40 +0.98	−4 −0.1		+4 +0.1	mV %
OUTPUT VOLTAGE TEMPERATURE DRIFT			100			50	ppm/°C
TEMPERATURE COEFFICIENT (TCV _O) −40°C < T_A < +125°C 0°C < T_A < 70°C		40 35	100		18 15	50	ppm/°C ppm/°C
MINIMUM SUPPLY HEADROOM ($V_{IN} - V_{OUT}$)	200			200			mV
LOAD REGULATION 0 mA < I_{OUT} < 5 mA (−40°C to +85°C) 0 mA < I_{OUT} < 5 mA (−40°C to +125°C) −5 mA < I_{OUT} < 0 mA (−40°C to +85°C) −5 mA < I_{OUT} < 0 mA (−40°C to +125°C) −0.1 mA < I_{OUT} < +0.1 mA (−40°C to +85°C) −0.1 mA < I_{OUT} < +0.1 mA (−40°C to +125°C)			0.32 0.52 0.40 0.6 3.2 4.1			0.32 0.52 0.40 0.6 3.2 4.1	mV/mA mV/mA mV/mA mV/mA mV/mA mV/mA
LINE REGULATION $V_{OUT} + 200$ mV < V_{IN} 12 V $I_{OUT} = 0$ mA			25			25	μV/V
RIPPLE REJECTION ($\Delta V_{OUT}/\Delta V_{IN}$) $V_{IN} = 5$ V ± 100 mV (f = 120 Hz)	80			80			dB
QUIESCENT CURRENT			70			70	μA
SHORT-CIRCUIT CURRENT TO GROUND			15			15	mA
NOISE VOLTAGE (at 25°C) 0.1 Hz to 10 Hz 10 Hz to 10 kHz		110 90			110 90		μV p-p μV rms
TURN-ON SETTLING TIME TO 0.1% $C_L = 0.2$ μF			140			140	μs
LONG-TERM STABILITY 1000 Hours at 25°C		100			100		ppm/1000 hr
OUTPUT VOLTAGE HYSTERESIS		115			115		ppm
TEMPERATURE RANGE Specified Performance (A, B) Operating Performance (A, B)	−40 −55		+125 −125	−40 −55		+125 +125	°C °C

AD1585 SPECIFICATIONS

$T_A = T_{MIN}$ to T_{MAX} , $V_{IN} = 6$ V, unless otherwise noted.

Table 5.

Parameter	AD1585A			AD1585B			Unit
	Min	Typ	Max	Min	Typ	Max	
OUTPUT VOLTAGE (at 25°C) V_O	4.950	5.000	5.050	4.995	5.000	5.005	V
INITIAL ACCURACY ERROR (at 25°C) V_{OERR}	−50 −1.0		+50 +1.0	−5 −0.10		+5 +0.10	mV %
OUTPUT VOLTAGE TEMPERATURE DRIFT			100			50	ppm/°C
TEMPERATURE COEFFICIENT (TCV _O) −40°C < T_A < 125°C 0°C < T_A < 70°C		40 35	100		18 15	50	ppm/°C ppm/°C
MINIMUM SUPPLY HEADROOM ($V_{IN} - V_{OUT}$)	200			200			mV
LOAD REGULATION 0 mA < I_{OUT} < 5 mA (−40°C to +85°C) 0 mA < I_{OUT} < 5 mA (−40°C to +125°C) −5 mA < I_{OUT} < 0 mA (−40°C to +85°C) −5 mA < I_{OUT} < 0 mA (−40°C to +125°C) −0.1 mA < I_{OUT} < +0.1 mA (−40°C to +85°C) −0.1 mA < I_{OUT} < +0.1 mA (−40°C to +125°C)			0.40 0.6 0.40 0.6 4 4.8			0.40 0.6 0.40 0.6 4 4.8	mV/mA mV/mA mV/mA mV/mA mV/mA mV/mA
LINE REGULATION $V_{OUT} + 200$ mV < V_{IN} < 12 V $I_{OUT} = 0$ mA			25			25	μV/V
RIPPLE REJECTION ($\Delta V_{OUT}/\Delta V_{IN}$) $V_{IN} = 6$ V ± 100 mV (f = 120 Hz)	80			80			dB
QUIESCENT CURRENT			70			70	μA
SHORT-CIRCUIT CURRENT TO GROUND			15			15	mA
NOISE VOLTAGE (at 25°C) 0.1 Hz to 10 Hz 10 Hz to 10 kHz		140 100			140 100		μV p-p μV rms
TURN-ON SETTLING TIME TO 0.1% $C_L = 0.2$ μF			175			175	μs
LONG-TERM STABILITY 1000 Hours at 25°C		100			100		ppm/1000 hr
OUTPUT VOLTAGE HYSTERESIS		115			115		ppm
TEMPERATURE RANGE Specified Performance (A, B) Operating Performance (A, B)	−40 −55		+125 +125	−40 −55		+125 +125	°C °C

ABSOLUTE MAXIMUM RATINGS

Table 6.

Parameter	Rating
V _{IN} to Ground	12 V
Internal Power Dissipation ¹ SOT-23-3 (RT-3)	400 mW
Storage Temperature Range	–65°C to 150°C
Specified Temperature Range AD1582RT/AD1583RT/ AD1584RT/AD1585RT	–40°C to +125°C
Lead Temperature, Soldering Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

¹ This specification is for a device in free air at 25°C; for a SOT-23 package, $\theta_{JA} = 300^{\circ}\text{C/W}$.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TERMINOLOGY

Temperature Coefficient (TCV_O)

The change of output voltage over the operating temperature change and normalized by the output voltage at 25°C, expressed in ppm/°C. The equation follows

$$TCV_O [\text{ppm}/^\circ\text{C}] = \frac{V_O(T_2) - V_O(T_1)}{V_O(25^\circ\text{C}) \times (T_2 - T_1)} \times 10^6$$

where:

$V_O(25^\circ\text{C}) = V_O$ at 25°C.

$V_O(T_1) = V_O$ at Temperature 1.

$V_O(T_2) = V_O$ at Temperature 2.

Line Regulation ($\Delta V_O/\Delta V_{IN}$) Definition

The change in output voltage due to a specified change in input voltage. It includes the effects of self-heating. Line regulation is expressed in either percent per volt, parts per million per volt, or microvolts per volt change in input voltage.

Load Regulation ($\Delta V_O/\Delta I_{LOAD}$)

The change in output voltage due to a specified change in load current. It includes the effects of self-heating. Load regulation is expressed in either microvolts per milliamper, parts per million per milliamper, or ohms of dc output resistance.

Long-Term Stability (ΔV_O)

Typical shift of output voltage at 25°C on a sample of parts subjected to an operation life test of 1000 hours at 125°C.

$$\Delta V_O = V_O(t_0) - V_O(t_1)$$

$$\Delta V_O [\text{ppm}] = \frac{V_O(t_0) - V_O(t_1)}{V_O(t_0)} \times 10^6$$

where:

$V_O(t_0) = V_O$ at 25°C at Time 0.

$V_O(t_1) = V_O$ at 25°C after 1000 hours of operation at 125°C.

Thermal Hysteresis (V_{O_HYS})

The change of output voltage after the device is cycled through temperatures from +25°C to -40°C to +85°C and back to +25°C.

This is a typical value from a sample of parts put through such a cycle

$$V_{O_HYS} = V_O(25^\circ\text{C}) - V_{O_TC}$$

$$V_{O_HYS} [\text{ppm}] = \frac{V_O(25^\circ\text{C}) - V_{O_TC}}{V_O(25^\circ\text{C})} \times 10^6$$

where:

$V_O(25^\circ\text{C}) = V_O$ at 25°C.

$V_{O_TC} = V_O$ at 25°C after temperature cycle at +25°C to -40°C to +85°C and back to +25°C.

Operating Temperature

The temperature extremes at which the device can still function. Parts can deviate from their specified performance outside the specified temperature range.

TYPICAL PERFORMANCE CHARACTERISTICS

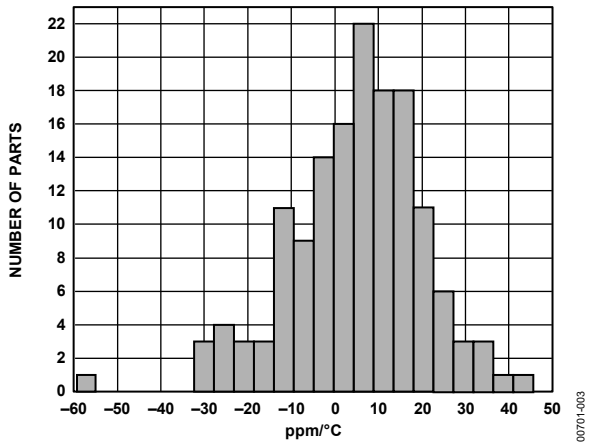


Figure 3. Typical Output Voltage Temperature Drift Distribution

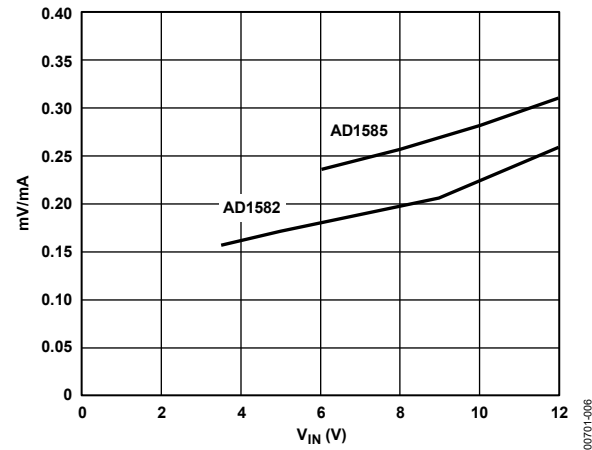
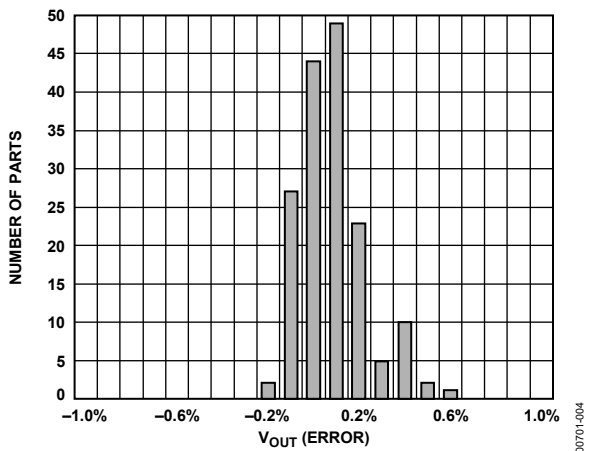
Figure 6. Load Regulation vs. V_{IN} 

Figure 4. Typical Output Voltage Error Distribution

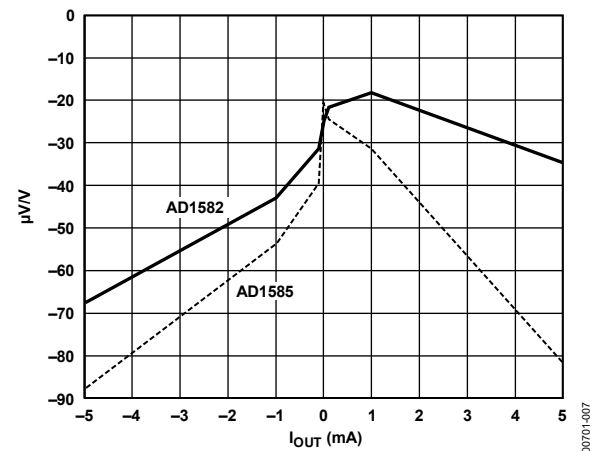
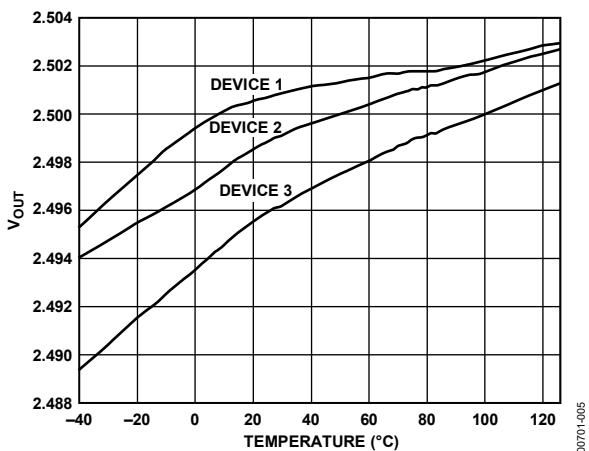
Figure 7. Line Regulation vs. I_{LOAD} 

Figure 5. Typical Temperature Drift Characteristic Curves

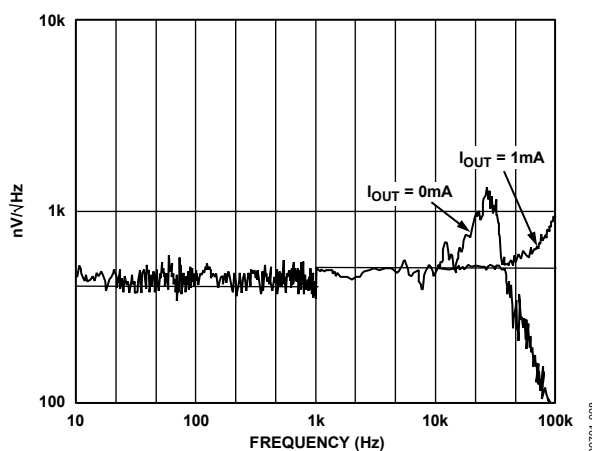


Figure 8. Noise Spectral Density

THEORY OF OPERATION

The AD1582/AD1583/AD1584/AD1585 use the band gap concept to produce stable, low temperature coefficient voltage references suitable for high accuracy data acquisition components and systems. These parts of precision references use the underlying temperature characteristics of a silicon transistor's base emitter voltage in the forward-biased operating region. Under this condition, all such transistors have a $-2 \text{ mV}/^{\circ}\text{C}$ temperature coefficient (TC) and a V_{BE} that, when extrapolated to absolute zero, 0 K (with collector current proportional to absolute temperature), approximates the silicon band gap voltage. By summing a voltage that has an equal and opposite temperature coefficient of $2 \text{ mV}/^{\circ}\text{C}$ with the V_{BE} of a forward-biased transistor, an almost 0 TC reference can be developed. In the AD1582/AD1583/AD1584/AD1585 simplified circuit diagram shown in Figure 9, such a compensating voltage, V_1 , is derived by driving two transistors at different current densities and amplifying the resultant V_{BE} difference (ΔV_{BE} , which has a positive TC). The sum of V_{BE} and V_1 (V_{BG}) is then buffered and amplified to produce stable reference voltage outputs of 2.5 V, 3 V, 4.096 V, and 5 V.

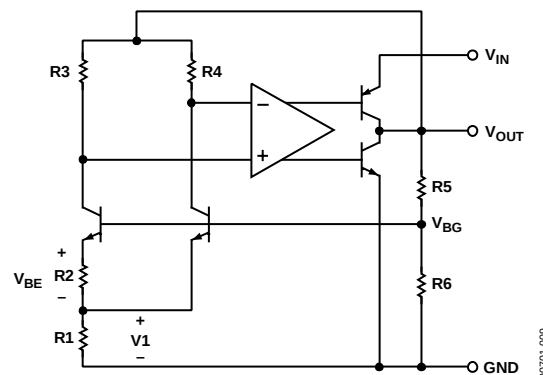


Figure 9. Simplified Schematic

00701-009

APPLICATIONS INFORMATION

The AD1582/AD1583/AD1584/AD1585 are series references that can be used for many applications. To achieve optimum performance with these references, only two external components are required. Figure 10 shows the AD1582/AD1583/AD1584/AD1585 configured for operation under all loading conditions. With a simple 4.7 μF capacitor attached to the input and a 1 μF capacitor applied to the output, the devices can achieve specified performance for all input voltage and output current requirements. For best transient response, add a 0.1 μF capacitor in parallel with the 4.7 μF capacitor. While a 1 μF output capacitor can provide stable performance for all loading conditions, the AD1582/AD1583/AD1584/AD1585 can operate under low ($-100 \mu\text{A} < I_{\text{OUT}} < +100 \mu\text{A}$) current conditions with just a 0.2 μF output capacitor. The 4.7 μF capacitor on the input can be reduced to 1 μF in this condition.

Unlike conventional shunt reference designs, the AD1582/AD1583/AD1584/AD1585 provide stable output voltages at constant operating current levels. When properly decoupled, as shown in Figure 10, these devices can be applied to any circuit and provide superior low power solutions.

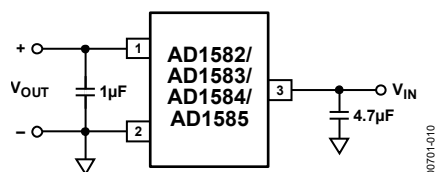


Figure 10. Typical Connection Diagram

TEMPERATURE PERFORMANCE

The AD1582/AD1583/AD1584/AD1585 are designed for applications where temperature performance is important. Extensive temperature testing and characterization ensure that device performance is maintained over the specified temperature range.

The error band guaranteed with the AD1582/AD1583/AD1584/AD1585 is the maximum deviation from the initial value at 25°C. Therefore, for a given grade of the AD1582/AD1583/AD1584/AD1585, the designer can easily determine the maximum total error by summing initial accuracy and temperature variation. For example, for the AD1582BRT, the initial tolerance is $\pm 2 \text{ mV}$, and the temperature error band is $\pm 8 \text{ mV}$; therefore, the reference is guaranteed to be $2.5 \text{ V} \pm 10 \text{ mV}$ from -40°C to $+125^\circ\text{C}$.

Figure 11 shows the typical output voltage drift for the AD1582/AD1583/AD1584/AD1585 and illustrates the methodology. The box in Figure 11 is bounded on the x-axis by operating temperature extremes. It is bounded on the y-axis by the maximum and minimum output voltages observed over the operating temperature range. The slope of the diagonal drawn from the initial output value at 25°C to the output values at $+125^\circ\text{C}$ and -40°C determines the performance grade of the device.

Duplication of these results requires a test system that is highly accurate with stable temperature control. Evaluation of the AD1582/AD1583/AD1584/AD1585 produces curves similar to those in Figure 5 and Figure 11, but output readings can vary depending on the test methods and test equipment used.

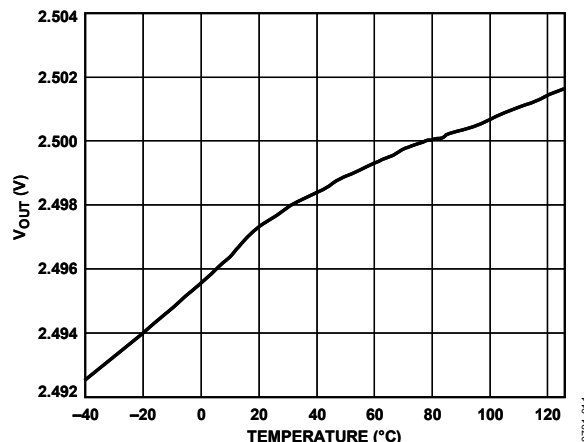


Figure 11. Output Voltage vs. Temperature

VOLTAGE OUTPUT NONLINEARITY VS. TEMPERATURE

When using a voltage reference with data converters, it is important to understand the impact that temperature drift can have on converter performance. The nonlinearity of the reference output drift represents additional error that cannot be easily calibrated out of the overall system. To better understand the impact such a drift can have on a data converter, refer to Figure 12, where the measured drift characteristic is normalized to the endpoint average drift. The residual drift error for the AD1582/AD1583/AD1584/AD1585 of approximately 200 ppm demonstrates that these parts are compatible with systems that require 12-bit accurate temperature performance.

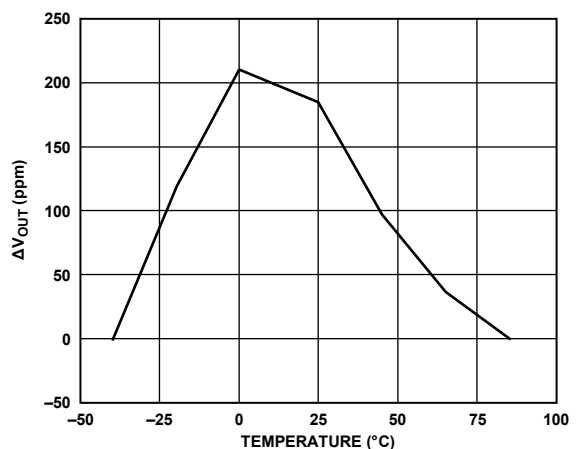


Figure 12. Residual Drift Error

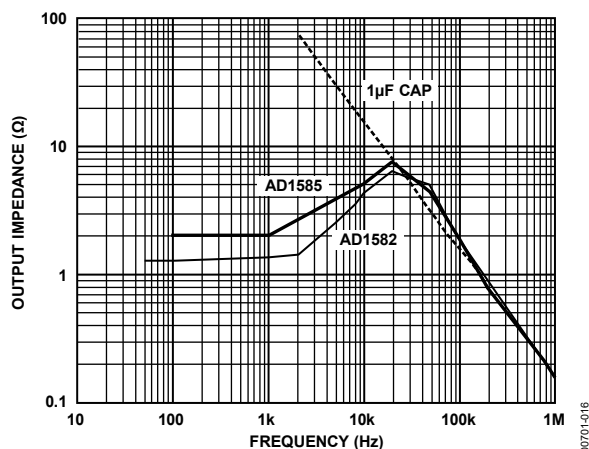


Figure 17. Output Impedance vs. Frequency

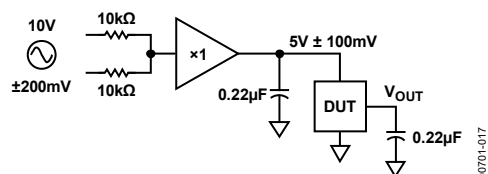


Figure 18. Ripple Rejection Test Circuit

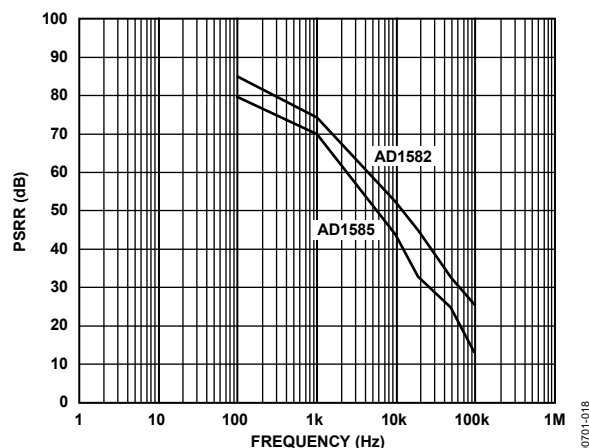


Figure 19. Ripple Rejection vs. Frequency

NOISE PERFORMANCE AND REDUCTION

The noise generated by the [AD1582/AD1583/AD1584/AD1585](#) is typically less than 70 μV p-p over the 0.1 Hz to 10 Hz frequency band. Figure 20 shows the 0.1 Hz to 10 Hz noise of a typical [AD1582/AD1583/AD1584/AD1585](#). The noise measurement is made with a high gain band-pass filter. Noise in a 10 Hz to 10 kHz region is approximately 50 μV rms. Figure 21 shows the broadband noise of a typical [AD1582/AD1583/AD1584/AD1585](#). If further noise reduction is desired, add a 1-pole, low-pass filter between the output pin and ground. A time constant of 0.2 ms has a -3 dB point at roughly 800 Hz and reduces the high frequency noise to about 16 μV rms. It should be noted, however, that while additional filtering on the output can improve the noise performance of the [AD1582/AD1583/AD1584/AD1585](#), the added output impedance can degrade the ac performance of the references.

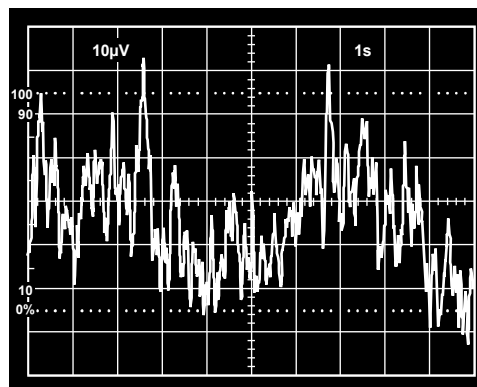


Figure 20. 10 Hz to 10 kHz Wideband Noise

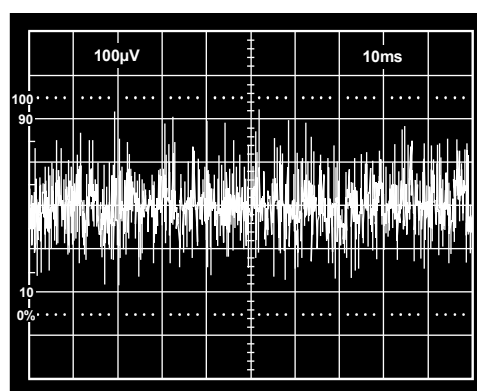


Figure 21. 1 Hz to 10 Hz Voltage Noise

TURN-ON TIME

Many low power instrument manufacturers are concerned with the turn-on characteristics of the components used in their systems. Fast turn-on components often enable the end user to save power by keeping power off when not needed. Turn-on settling time is defined as the time required, after the application of power (cold start), for the output voltage to reach its final value within a specified error. The two major factors affecting this are the active circuit settling time and the time required for the thermal gradients on the chip to stabilize. Figure 22 shows the turn-on settling and transient response test circuit. Figure 23 shows the turn-on characteristics of the [AD1582/AD1583/AD1584/AD1585](#). These characteristics are generated from cold-start operation and represent the true turn-on waveform after power-up. Figure 24 shows the fine settling characteristics of the [AD1582/AD1583/AD1584/AD1585](#). Typically, the reference settles to within 0.1% of its final value in about 100 μs .

The device can momentarily draw excessive supply current when V_{SUPPLY} is slightly below the minimum specified level. Power supply resistance must be low enough to ensure reliable turn-on. Fast power supply edges minimize this effect.

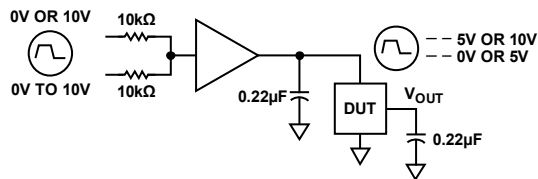


Figure 22. Turn-On/Transient Response Test Circuit

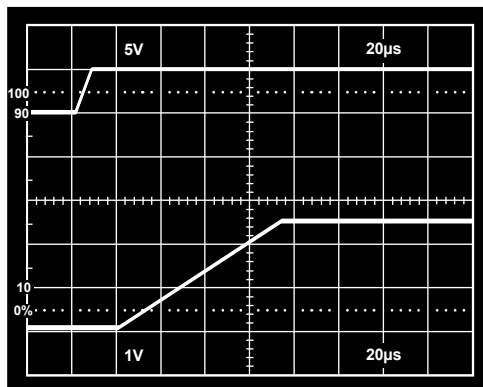


Figure 23. Turn-On Characteristics

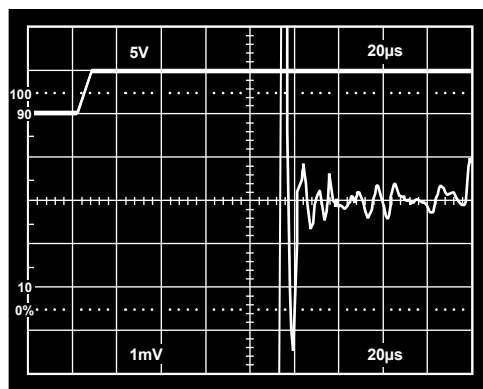


Figure 24. Turn-On Settling

DYNAMIC PERFORMANCE

Many ADCs and DACs present transient current loads to the reference and poor reference response can degrade converter performance. The AD1582/AD1583/AD1584/AD1585 provide superior static and dynamic line and load regulation. Because these series references are capable of both sourcing and sinking large current loads, they exhibit excellent settling characteristics.

Figure 25 displays the line transient response for the AD1582/AD1583/AD1584/AD1585. The circuit used to perform such a measurement is shown in Figure 22, where the input supply voltage is toggled from 5 V to 10 V, and the input and output capacitors are each 0.22 μ F.

Figure 26 and Figure 27 show the load transient settling characteristics for the AD1582/AD1583/AD1584/AD1585 when load current steps of 0 mA to +5 mA and 0 mA to –1 mA are applied. The input supply voltage remains constant at 5 V; the input decoupling and output load capacitors are 4.7 μ F and 1 μ F, respectively; and the output current is toggled. For both positive and negative current loads, the reference responses settle very quickly and exhibit initial voltage spikes of less than 10 mV.

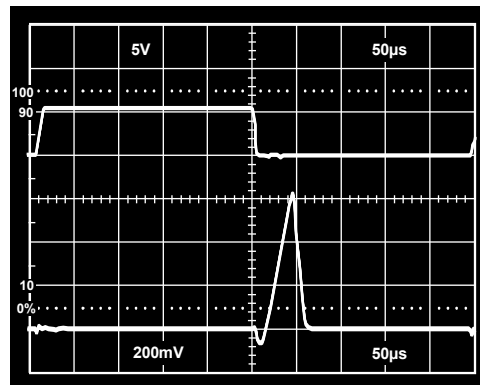


Figure 25. Line Transient Response

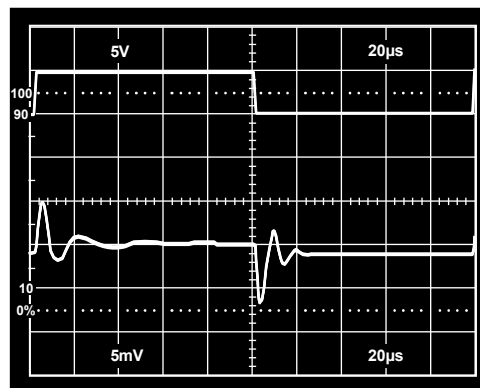


Figure 26. Load Transient Response (0 mA to 5 mA Load)

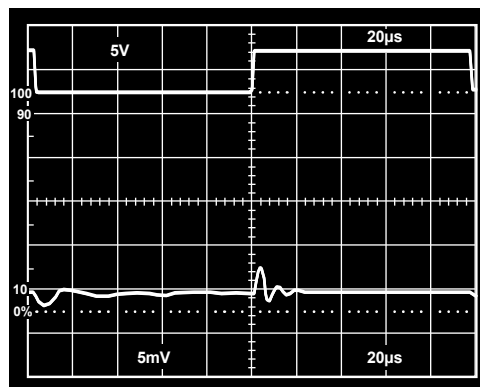
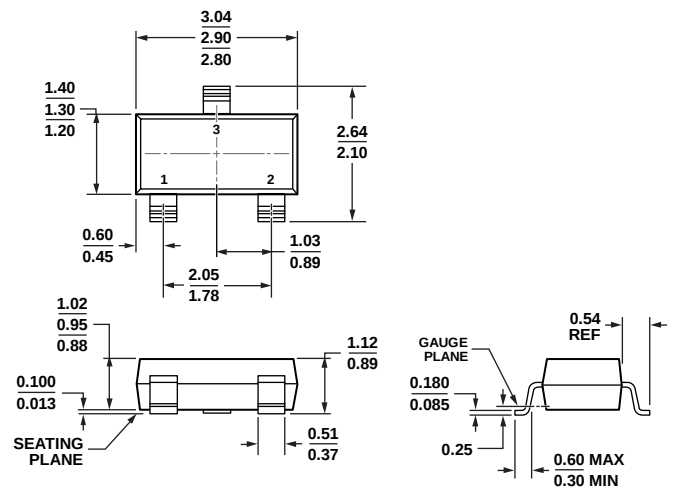


Figure 27. Load Transient Response (0 mA to –1 mA Load)

OUTLINE DIMENSIONS

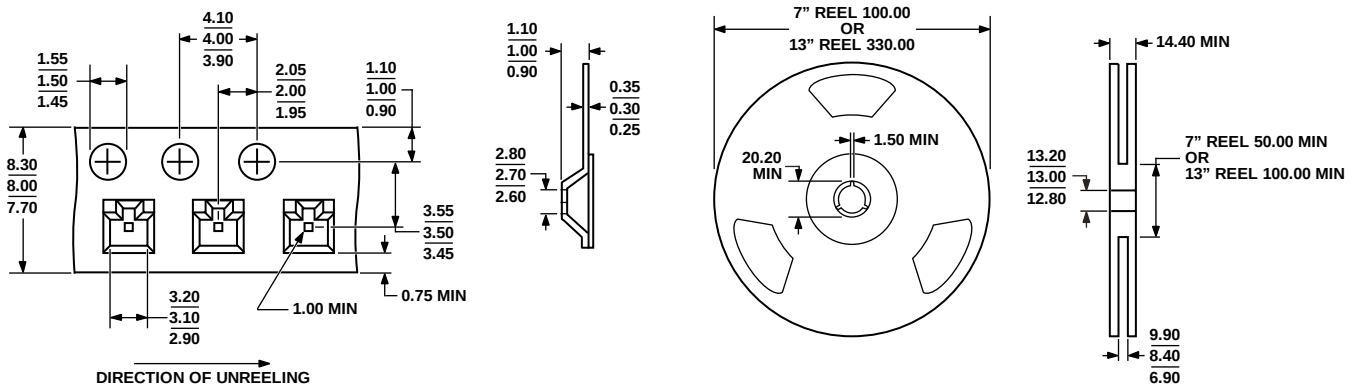


COMPLIANT TO JEDEC STANDARDS TO-236-AB

Figure 28. 3-Lead Small Outline Transistor Package [SOT-23-3]
(RT-3)

Dimensions shown in millimeters

011909-C

Figure 29. SOT-23 Tape and Reel Outline Dimension
(RT-3)

Dimensions shown in millimeters

053006-0

ORDERING GUIDE

Model ^{1,2}	Output Voltage (V)	Accuracy (mV)	Initial Accuracy (%)	Initial Temperature Coefficient (ppm/°C)	Package Description	Package Option	Marking Code	No. of Parts Banding per Reel
AD1582ARTZ-REEL7	2.50	20	0.80	100	SOT-23-3	RT-3	R1Z	3,000
AD1582BRTZ-REEL7	2.50	2	0.08	50	SOT-23-3	RT-3	R20	3,000
AD1582WBRTZ-R7	2.50	6	0.24	50	SOT-23-3	RT-3	R20	3,000
AD1583ARTZ-REEL7	3.00	30	1.00	100	SOT-23-3	RT-3	R22	3,000
AD1583BRTZ-REEL7	3.00	3	0.10	50	SOT-23-3	RT-3	R23	3,000
AD1583WBRTZ-R7	3.00	8	0.27	50	SOT-23-3	RT-3	R23	3,000
AD1584ARTZ-REEL7	4.096	40	0.98	100	SOT-23-3	RT-3	R25	3,000
AD1584BRTZ-REEL7	4.096	4	0.10	50	SOT-23-3	RT-3	R26	3,000
AD1585ARTZ-REEL7	5.00	50	1.00	100	SOT-23-3	RT-3	R28	3,000
AD1585BRTZ-REEL7	5.00	5	0.10	50	SOT-23-3	RT-3	R29	3,000

¹ Z = RoHS Compliant Part.² W = Qualified for Automotive Applications.

AUTOMOTIVE APPLICATIONS

The [AD1582W](#) and [AD1583W](#) models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

